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## Inclosure Material:

Metal

**Overall Length:** 

2.637 inches

# **Mounting Facility Quantity:**

1

### Internal Configuration:

Junction contact

### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-83

### **Mounting Method:**

Threaded stud

### **Features Provided:**

Hermetically sealed case and quality assurance level txv

### **Overall Width Across Flats:**

1.227 inches

#### **Thread Size:**

0.500 inches

### Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

300.0 repetitive peak reverse voltage and 300.0 repetitive peak off-state voltage and 400.0 nonrepetitive peak reverse voltage

### **Current Rating Per Characteristic:**

50.00 amperes forward current, total rms universal

### **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector blank

### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

### **Special Features:**

Junction pattern arrangement: pnpn

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### **Thread Series Designator:**

Unf

Terminal Type And Quantity: 2 tab, solder lug and 1 threaded stud Specification Data: 81349-mil-s-19500/204 government specification

## Shelf Life:

N/a

- Unit Of Measure:
- ---

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Demilitarization:

No

Fiig:

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